

Advance Technical Information

Trench™ **Power MOSFET**

IXUV170N075 IXUV170N075S

N-Channel Enhancement Mode

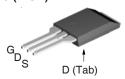


Symbol	Test Conditions	Maximum	Ratings
V _{DSS}	$T_J = 25^{\circ}C \text{ to } 175^{\circ}C$	75	V
V _{DGR}	$T_J = 25$ °C to 175°C, $R_{GS} = 1M\Omega$	75	V
V_{gss}	Continuous	± 20	V
V _{GSM}	Transient	± 30	V
I _{D25}	T _C = 25°C	170	A
ILRMS	Lead Current Limit, RMS	120	Α
I _{DM}	$T_{c} = 25^{\circ}C$, Pulse Width Limited by T_{JM}	300	Α
P _D	T _C = 25°C	310	W
T _J		-55 +175	°C
T _{JM}		175	°C
T _{stg}		-55 +175	°C
T,	Maximum Lead Temperature for Soldering	g 300	°C
T _{SOLD}	1.6 mm (0.062in.) from Case for 10s	260	°C
F _c	Mounting force (PLUS220)	1165 / 2.514.6	N/lb
Weight		4	g

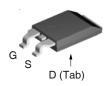
Symbol Test Conditions (T _J = 25°C Unless Otherwise Specified)		Characteristic Values Min. Typ. Max.			
BV _{DSS}	$V_{GS} = 0V, I_D = 250\mu A$	75			V
V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 1 \text{mA}$	2.0		4.0	V
I _{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			± 200	nA
I _{DSS}	$V_{DS} = V_{DSS}$, $V_{GS} = 0V$ $T_{J} = 150^{\circ}C$			5 500	μ Α μ Α
R _{DS(on)}	$V_{GS} = 10V$, $I_D = 0.5 \bullet I_{D25}$, Note 1			6.5	mΩ

75V 170A D25 $6.5 m\Omega$ $\mathbf{R}_{\mathrm{DS(on)}}$

PLUS220 (IXUV)



PLUS220SMD (IXUV_S)



G = Gate D = Drain S = Source Tab = Drain

Features

- International Standard Packages
- Fast Intrinsic Rectifier
- Low R_{DS(ON)} and Q_G
 Low Package Inductance

Advantages

- High Power Density
- Easy to Mount
- Space Savings

Applications

- Automotive 42V & 12V Systems
- Electronic Switches to Replace Relays and Fuses
- Choppers to Replace Series Dropping Resistors used for Motors, Heaters, etc.
- Inverters for AC Drives, e.g. Starter Generator
- DC DC Inverters
- Power Supplies
 - DC DC Inverters
 - Solar Inverters
- Battery Powered Systems
 - Choppers or Inverters for Motor Control in Hand Tools
 - Battery Chargers



Symbol (T _J = 25°C	Test Conditions Unless Otherwise Specified)	Cha Min.	racterist Typ.	ic Values Max.
C _{iss}			TBD	pF
C _{oss}	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		TBD	pF
C _{rss}			TBD	pF
t _{d(on)}	Decistive Cuitabing Times		50	ns
t,	Resistive Switching Times		40	ns
t _{d(off)}	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$		190	ns
t _f	$R_{\rm G} = 4.7\Omega$ (External)		55	ns
$Q_{g(on)}$			250	nC
Q _{gs}	$V_{GS} = 10V$, $V_{DS} = 0.5 \cdot V_{DSS}$, $I_{D} = 0.5 \cdot I_{D25}$		TBD	nC
Q_{gd}			TBD	nC
R _{thJC}				0.98 ºC/W
$\mathbf{R}_{\mathrm{thJC}}$			0.21	°C/W

Source-Drain Diode

Symbol	Test Conditions	Characteristic Values			
$T_{\rm J} = 25^{\circ}$ C	Unless Otherwise Specified)	Min.	Тур.	Max.	
I _s	$V_{GS} = 0V$			170	Α
I _{sm}	Repetitive, pulse width limited by $T_{_{JM}}$			680	Α
V _{SD}	$I_F = 85A$, $V_{GS} = 0V$, Note 1			1.5	V
t _{rr}	$I_F = 85A$, -di/dt = 250A/ μ s		120		ns
	$V_{R} = 37.5 V, V_{GS} = 0 V$				

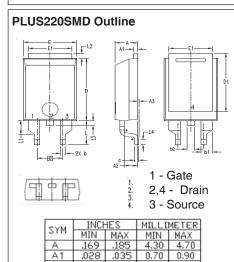
Note 1. Pulse test, $t \le 300\mu s$, duty cycle, $d \le 2\%$.

ADVANCE TECHNICAL INFORMATION

The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

PLUS220 Outline 1 - Gate 2,4 - Drain 3 - Source

SYM	INCHES		MILLIMETER	
2114	MIN	MAX	MIN	MAX
Α	.169	.185	4.30	4.70
A1	.028	.035	0.70	0.90
A2	.098	.118	2.50	3.00
Ь	.035	.047	0.90	1.20
Ь1	.080	.095	2.03	2.41
b2	.054	.064	1.37	1.63
C	.028	.035	0.70	0.90
D	.551	.591	14.00	15.00
D1	.512	.539	13.00	13.70
E	.394	.433	10.00	11.00
E1	.331	.346	8.40	8.80
e	.100BSC		2.54 BSC	
L	.512	.551	13.00	14.00
L1	.118	.138	3.00	3,50
L2	.035	.051	0.90	1.30
L3	.047	.059	1.20	1.50



SYM	INCHES		MILLIMETER		
STH	MIN	MAX	MIN	MAX	
Α	.169	.185	4.30	4.70	
A1	.028	.035	0.70	0.90	
A2	.098	.118	2.50	3.00	
A3	.000	.010	0.00	0.25	
Ь	.035	.047	0.90	1.20	
ь1	.080	.095	2.03	2.41	
Ь2	.054	.064	1.37	1.63	
С	.028	.035	0.70	0.90	
D	.551	.591	14.00	15.00	
D1	.512	.539	13.00	13.70	
E	.394	.433	10.00	11.00	
E1	.331	.346	8.40	8.80	
е	.20	.200BSC		5.08 BSC	
L	.209	.228	5.30	5.80	
L1	.118	.138	3.00	3.50	
L2	.035	.051	0.90	1.30	
L3	.047	.059	1.20	1.50	
L4	.039	.059	1.00	1.50	

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